NSN 5961-01-101-7564

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-101-7564 **Inclosure Material:** Plastic **Overall Length:** Between 0.660 inches and 0.785 inches **Overall Height:** Between 0.140 inches and 0.180 inches Overall Width: Between 0.220 inches and 0.280 inches **Component Name And Quantity:** 4 transistor **Mounting Method:** Press fit **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 collector to emitter voltage, dc all transistor and 60.0 collector to emitter reverse voltage all transistor and 40.0 collector to emitter voltage/static/base open all transistor **Current Rating Per Characteristic:** 1.50 amperes source cutoff current horsepower metric all transistor **Power Rating Per Characteristic:** 750.0 milliwatts small-signal input power, common-collector preset all transistor **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 14 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: